Preferred Device

Sidac High Voltage

Bidirectional Triggers

Bi-directional devices designed for direct interface with the ac power line. Upon reaching the breakover voltage in each direction, the device switches from a blocking state to a low voltage on–state. Conduction will continue like a Triac until the main terminal current drops below the holding current. The plastic axial lead package provides high pulse current capability at low cost. Glass passivation insures reliable operation. Applications are:

- High Pressure Sodium Vapor Lighting
- Strobes and Flashers
- Ignitors
- High Voltage Regulators
- Pulse Generators
- Used to Trigger Gates of SCR's and Triacs
- **%** Indicates UL Registered File #E116110
- Device Marking: Logo, Device Type, e.g., MKP1V120, Date Code

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Repetitive Off–State Voltage (Sine Wave, 50 to 60 Hz, T _J = -40 to 125°C) MKP1V120, MKP1V130, MKP1V160 MKP1V240	V _{DRM} , V _{RRM}	±90 ±180	Volts
On-State Current RMS (T _L = 80°C, Lead Length = 3/8", All Conduction Angles)	l _{T(RMS)}	±0.9	Amp
Peak Non–repetitive Surge Current (60 Hz One Cycle Sine Wave, T _J = 125°C)	ITSM	±4.0	Amps
Operating Junction Temperature Range	TJ	-40 to +125	°C
Storage Temperature Range	T _{stg}	-40 to +150	°C



ON Semiconductor

http://onsemi.com

SIDACS (%) 0.9 AMPERES RMS 120 thru 240 VOLTS





ORDERING INFORMATION

Device	Package	Shipping
201100	1 donago	oppg
MKP1V120RL	DO41	Tape and Reel 5K/Reel
MKP1V130RL	DO41	Tape and Reel 5K/Reel
MKP1V160	DO41	Bulk 1K/Bag
MKP1V160RL	DO41	Tape and Reel 5K/Reel
MKP1V240	DO41	Bulk 1K/Bag
MKP1V240RL	DO41	Tape and Reel 5K/Reel

Preferred devices are recommended choices for future use and best overall value.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Lead Lead Length = 3/8"	$R_{ heta JL}$	40	°C/W
Lead Solder Temperature (Lead Length ≥ 1/16" from Case, 10 s Max)	TL	260	°C

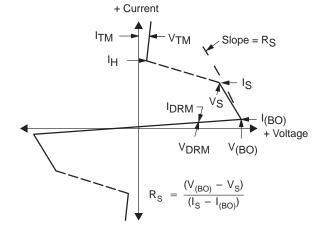
ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted; Electricals apply in both directions)

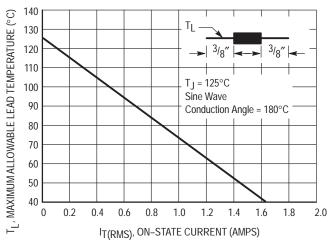
Characteristic	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS		•	'	•		•
Repetitive Peak Off–State Current (50 to 60 Hz Sine Wave) $V_D = 90 \text{ V, MKP1V120, MKP1V130 and MKP1V16}$ $V_D = 180 \text{ V, MKP1V240}$	T _J = 25°C	I _{DRM}	-	_	5.0	μА
ON CHARACTERISTICS		•	•			
Breakover Voltage	MKP1V120 MKP1V130 MKP1V160 MKP1V240	Vво	110 120 150 220		130 140 170 250	Volts
Peak On–State Voltage (I _{TM} = 1 A Peak, Pulse Width ≤ 300 μs, Duty Cycle	e ≤ 2%)	V _{TM}		1.3	1.5	Volts
Dynamic Holding Current (Sine Wave, 50 to 60 Hz, R _L = 100 Ohm)		lн	_	_	100	mA
Switching Resistance (Sine Wave, 50 to 60 Hz)		R _S	0.1	_	_	kΩ
Breakover Current @ VBO		I _{BO}	T -		200	μА
DYNAMIC CHARACTERISTICS			-			
Critical Rate–of–Rise of On–State Current, Critical Damped Waveform Circuit (Ip _K = 130 Amps, Pulse Width = 10 μsec)		di/dt	50	120	130	A/μs

Voltage Current Characteristic of SIDAC (Bidirectional Device)

1.0

Symbol Parameter	
IDRM	Off State Leakage Current
VDRM	Off State Repetitive Blocking Voltage
V_{BO}	Breakover Voltage
IBO	Breakover Current
lΗ	Holding Current
V_{TM}	On State Voltage
I _{TM}	Peak on State Current

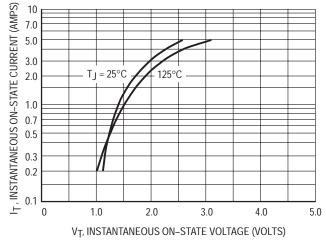




T_J = 125°C ¹T(RMS) , ON-STATE CURRENT (AMPS) Sine Wave 0.8 Conduction Angle = 180°C Assembled in PCB Lead Length = $\frac{3}{8}$ " 0.6 0.4 0.2 20 40 60 80 120 100 140 TA, MAXIMUM AMBIENT TEMPERATURE (°C)

Figure 1. Maximum Lead Temperature

Figure 2. Maximum Ambient Temperature



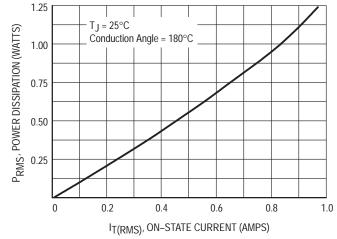


Figure 3. Typical On-State Voltage

Figure 4. Typical Power Dissipation

THERMAL CHARACTERISTICS

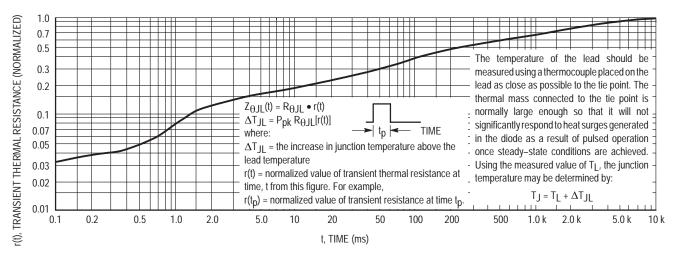


Figure 5. Thermal Response

TYPICAL CHARACTERISTICS

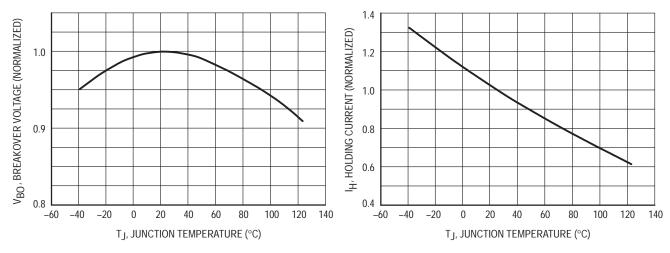


Figure 6. Typical Breakover Voltage

Figure 7. Typical Holding Current

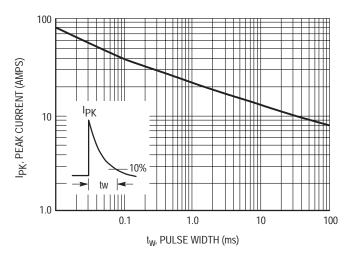
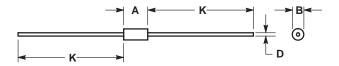


Figure 8. Pulse Rating Curve

PACKAGE DIMENSIONS

DO-41 PLASTIC AXIAL (No Polarity) CASE 059A-01 ISSUE A



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.

		INCHES		MILLIN	IETERS	
	DIM	M MIN MAX		MIN	MAX	
	Α	0.235	0.260	5.97	6.60	
	В	0.110	0.120	2.79	3.05	
ĺ	D	0.030	0.034	0.76	0.86	
ı	К	1.100		27.94		





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